

1. INDUCTANCE: @ 10 kHz, 0.1 Vrms,
1 - 3 > 225 uHy

$$1 - 3 = 0.1$$
$$4 - 6 = 0.1$$

3. LEAKAGE INDUCTANCE: 1 - 3, 1.0 V @ 100kHz
SHORT 4 - 6 < 0.7 uHy

4. INTERWINDING CAPACITANCE: with Shield Grounded

1 - 3 to 4 - 6 @ 100 KHz, 1.0V < 2.0 pf

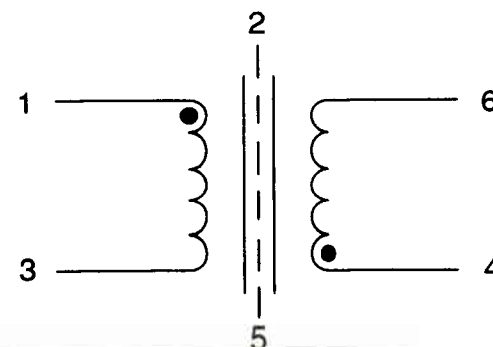
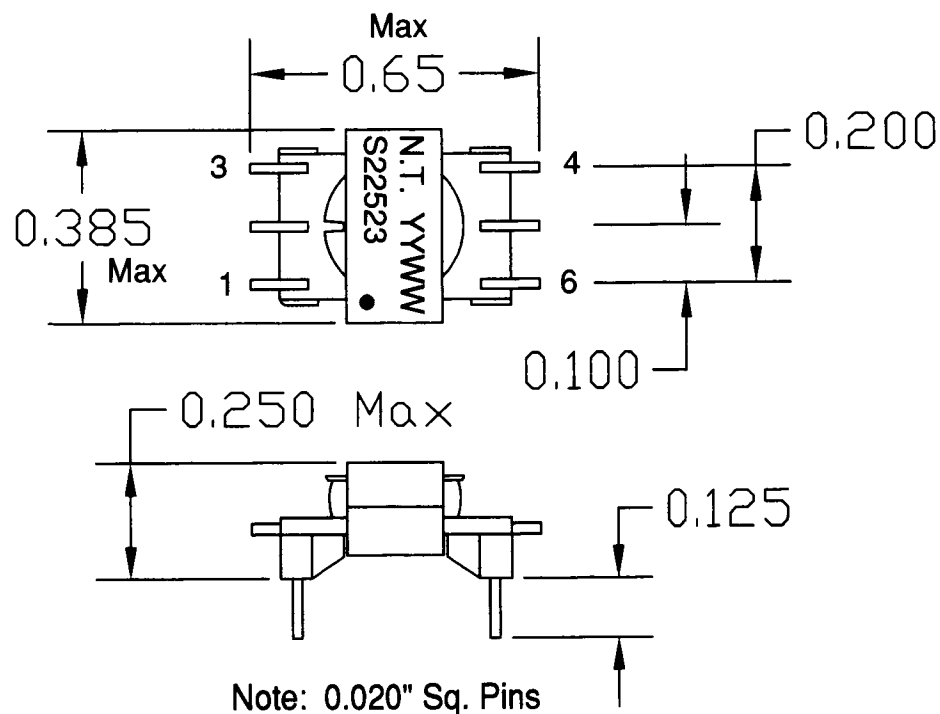
5. TURNS AND PHASE:

$$1 - 3 : 4 - 6 = 1 : 1.22 \pm 2\%$$

6 DIELECTRIC STRENGTH:

1500 VAC 1 sec

**Note: Designed to operate with Crystal Semiconductor
CS8401, 8402, 8411 & 8412**



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REV.	DATE	ECN	BY	DESCRIPTION			
TOLERANCES ON				Newava Tech. Watertown, SD 57201 605-886-0264		Transformer Power, 1:1.22	
.XXX + -	.XX + -	ANGLE + -					
			DATE				
DRAWN:			SCALE	MODEL	DRAWING NO.		REV.
CHECKED: -		-			S22523		A
APPROVED: -		-	NEXT ASSY:				
THIS PRINT MUST NOT BE COPIED IN WHOLE OR IN PART OR USED DETRIMENTALLY TO OUR INTEREST						SHEET 1 OF 1	